

- ✎ L9: (9) 7 same 8
- ✎ L10: (2281981) resistance
- ✎ L11: (418784) conductivity
- ✎ L12: (247761) 10 11
- ✎ L13: (17569) 2 near 8
- ✎ L14: (1186) 19 with 12
- ✎ L15: (61) 14 with 6
- ✎ L17: (2881835) large
- ✎ L18: (8098) 17 adj 10
- ✎ L19: (577) 6 with 19
- ✎ L21: (2) 8 same 19
- ✎ L23: (34883) 1 organic adj (light led el luminescen\$2 electroluminescen\$
- ✎ L24: (3) 20 and 29
- ✎ L22: (21) 8 and 19
- ✎ L25: (11) 10/796980
- ✎ L26: (261419) sony.as.
- ✎ L27: (5) 18 and 26
- ✎ L20: (16) 2 with 19
- ✎ L15: (135) 14 same 6
- ✎ L28: (19578) 3 with 12
- ✎ L29: (18) 28 same 8
- ✎ L30: (358) 28 and 8
- ✎ L31: (367478) large\$2
- ✎ L32: (1697) 28 with 31
- ✎ L33: (50) 32 and 0

April 2005

	U	S	Inventor	Document	Issue	P	Title	Current	Current	Retrieval	S	C	P	S	Image	Doc	P
1			Mikoshiba,	US 5225	27	1993	13	Transparent electroconductive lamination	428/32	428/212						US 522527	
2			Yamazaki, S	US 200500	2005	3	Light emitting device	313/50	313/500							US 20050	
3			Bao, Zhena	US 200500	2005	3	Semiconductor devices having regions	257/20								US 20050	
4			Kawasaki, U	US 200500	2005	13	Semiconductor device and manufacture	257/35								US 20050	
5			Shtein, Max	US 2004018	2004	16	Method of manufacturing high-mobility	438/89								US 200401	
6			Koo, Joo-Bo	US 2004018	2004	16	Flat panel display with thin film transis	345/82								US 200401	
7			Joshi, Rajiv	US 2004018	2004	12	Soft metal conductor and method of m	438/67	438/653							US 200401	
8			Hanekawa, Y	US 2004018	2004	4	Liquid crystal device, method for makin	349/71								US 200401	
9			Koyama, Ju	US 2004018	2004	3	Display device and method of driving th	345/70								US 200401	
10			Fujimoto, Et	US 2004014	2004	2	Light emitting device	257/72	257/12141							US 200401	